

2SK1629-E1-E

500V - 30A - MOS FET
High Speed Power Switching

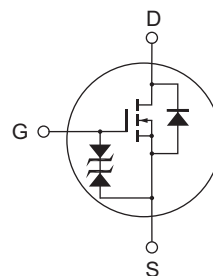
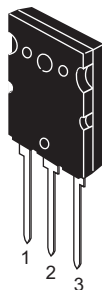
R07DS1197EJ0200
Rev.2.00
Mar 26, 2014

Features

- Low on-resistance
 $R_{DS(on)} = 0.22 \Omega$ typ. (at $I_D = 15 A$, $V_{GS} = 10 V$, $T_a = 25^\circ C$)
- High speed switching
- Low drive current
- Suitable for switching regulator and DC-DC converter

Outline

RENESAS Package code: PRSS0003ZC-A
(Package name:TO-264)



1. Gate
2. Drain
3. Source

Absolute Maximum Ratings

($T_a = 25^\circ C$)

Item	Symbol	Ratings	Unit
Drain to Source voltage	V_{DSS}	500	V
Gate to Source voltage	V_{GSS}	± 30	V
Drain current	I_D	30	A
Drain peak current	$I_{D(pulse)}$ ^{Note1}	120	A
Body-Drain diode reverse Drain current	I_{DR}	30	A
Channel dissipation	P_{ch} ^{Note2}	200	W
Channel temperature	T_{ch}	150	$^\circ C$
Storage temperature	T_{stg}	-55 to +150	$^\circ C$

Notes: 1. $PW \leq 10 \mu s$, duty cycle $\leq 1\%$
2. Value at $T_c = 25^\circ C$

Electrical Characteristics

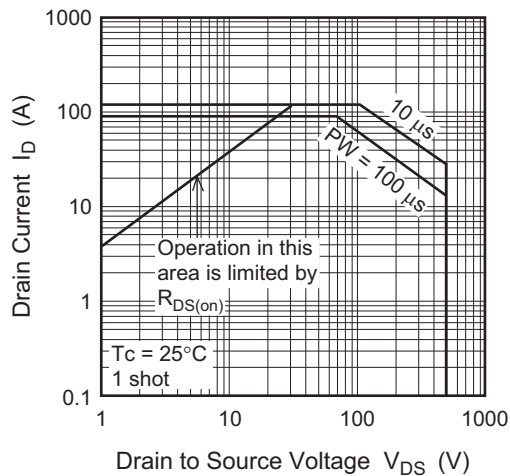
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	500	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 30	—	—	V	$I_G = \pm 100 \text{ }\mu\text{A}$, $V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 25 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	250	μA	$V_{DS} = 400 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	—	3.0	V	$I_D = 1 \text{ mA}$, $V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	0.22	0.27	Ω	$I_D = 15 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note3}
Forward transfer admittance	$ y_{fs} $	12	20	—	S	$I_D = 15 \text{ A}$, $V_{DS} = 10 \text{ V}$ ^{Note3}
Input capacitance	C_{iss}	—	2800	—	pF	$V_{DS} = 10 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	780	—	pF	
Reverse transfer capacitance	C_{rss}	—	90	—	pF	
Turn-on delay time	$t_{d(on)}$	—	32	—	ns	$I_D = 15 \text{ A}$, $V_{GS} = 10 \text{ V}$, $R_L = 2 \text{ }\Omega$
Rise time	t_r	—	140	—	ns	
Turn-off delay time	$t_{d(off)}$	—	200	—	ns	
Fall time	t_f	—	100	—	ns	
Body to drain diode forward voltage	V_{DF}	—	1.1	—	V	$I_F = 30 \text{ A}$, $V_{GS} = 0$
Body to drain diode reverse recovery time	t_{rr}	—	600	—	ns	$I_F = 30 \text{ A}$, $V_{GS} = 0$, $di_F/dt = 100 \text{ A}/\mu\text{s}$

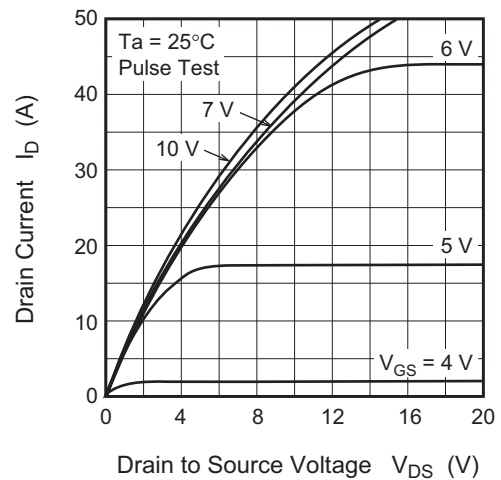
Note: 3. Pulse test

Main Characteristics

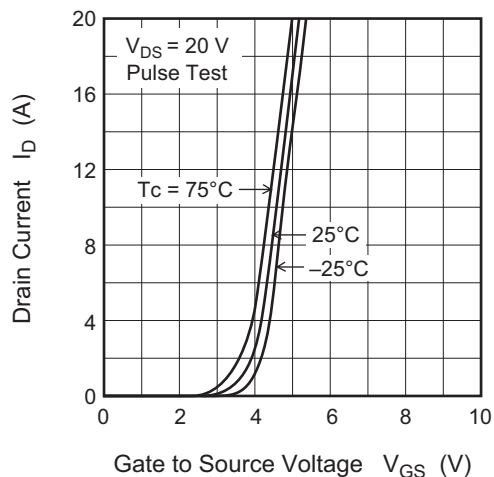
Maximum Safe Operation Area



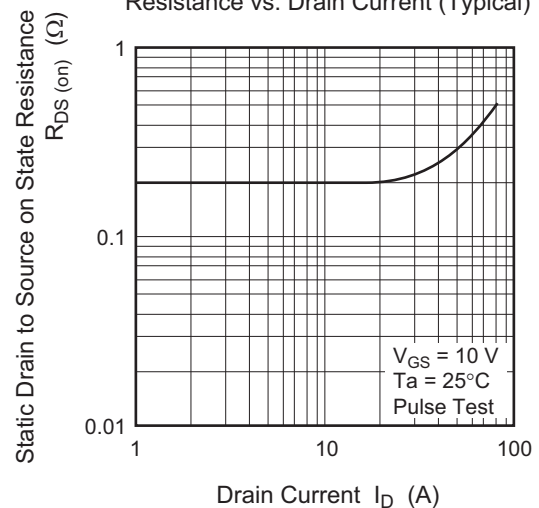
Typical Output Characteristics



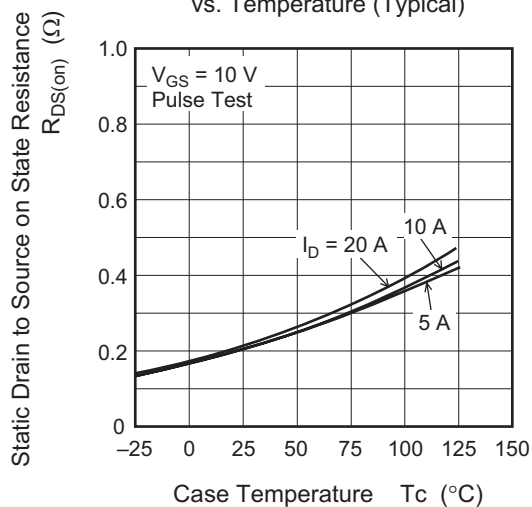
Typical Transfer Characteristics



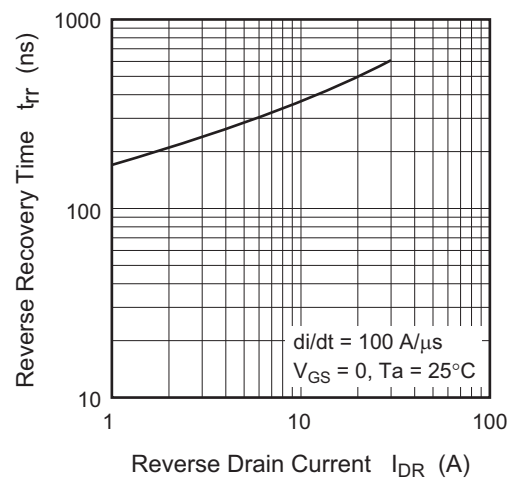
Static Drain to Source on State Resistance vs. Drain Current (Typical)



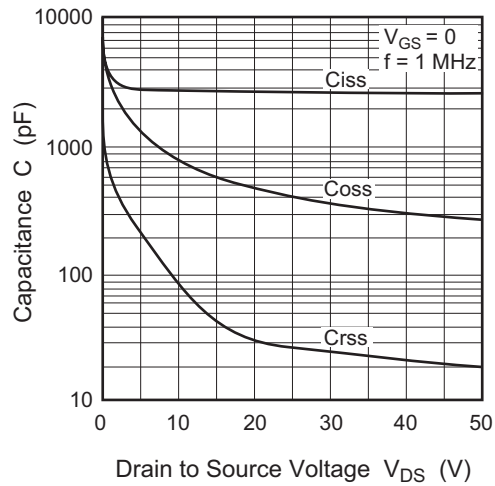
Static Drain to Source on State Resistance vs. Temperature (Typical)



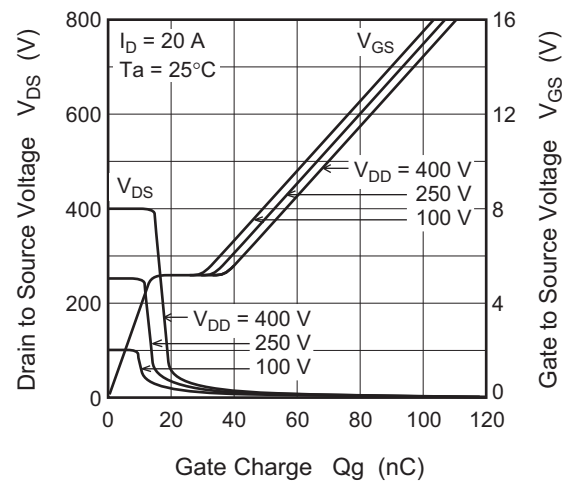
Body-Drain Diode Reverse Recovery Time (Typical)



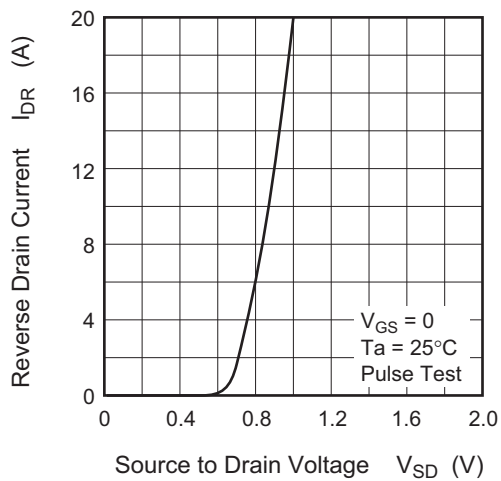
Typical Capacitance
vs. Drain to Source Voltage



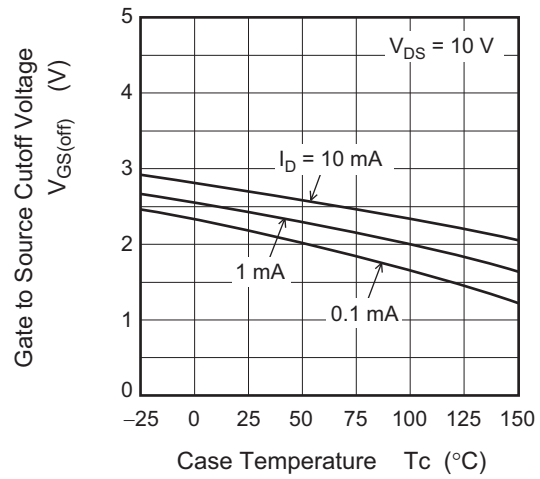
Dynamic Input Characteristics



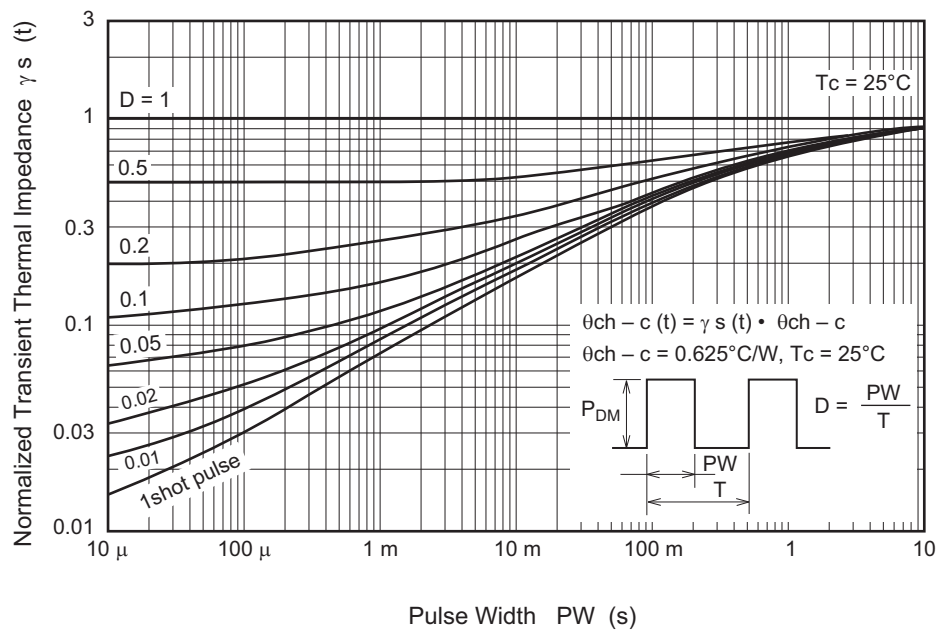
Reverse Drain Current vs.
Source to Drain Voltage (Typical)



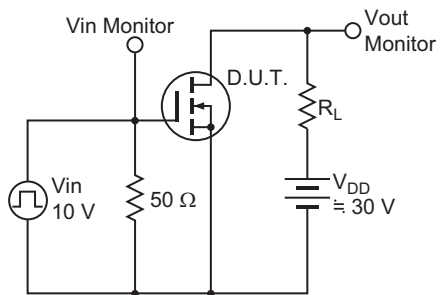
Gate to Source Cutoff Voltage
vs. Case Temperature (Typical)



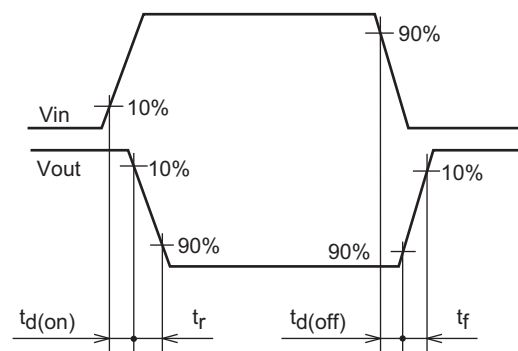
Normalized Transient Thermal Impedance vs. Pulse Width



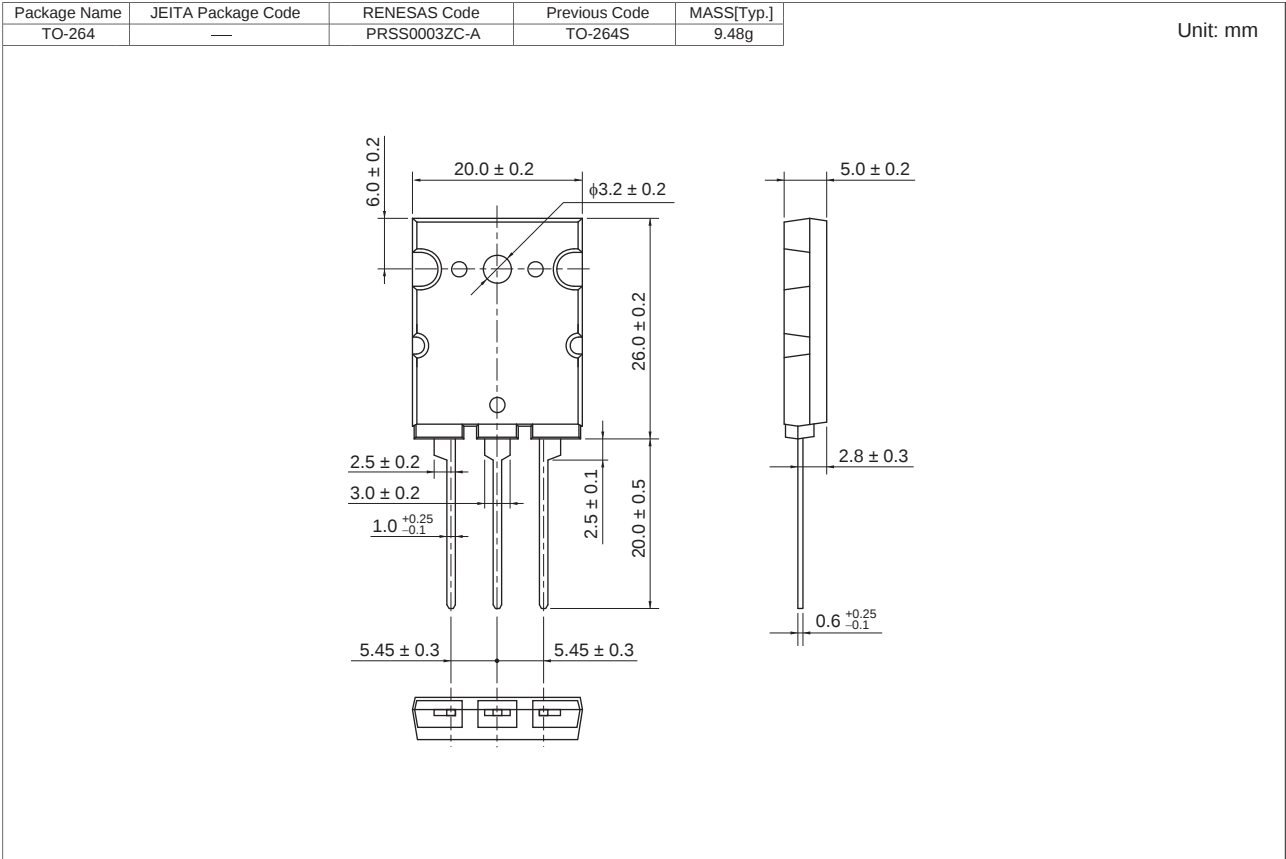
Switching Time Test Circuit



Waveform



Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
2SK1629-E1-E#T2	25 pcs	Tube

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